

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|--------|--|---|------------------|---------|------------------|
| L1 | 107409 | semiconductor near laser | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 10:37 |
| L2 | 25242 | l1 and (base submount) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 10:37 |
| L5 | 10 | l1 and ((base submount) near3 (width dimension)) and ((base submount) near2 (AlN or (aluminum adj nitride))) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 10:45 |
| L6 | 638 | l1 and ((base submount) near3 (width dimension)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 10:45 |